Lab 5. Research on DC drive PWM converters

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Part 1. Evaluate missing parameters

- Open Actuators Lab 5 R2022b.slx model and Actuators Lab5 R20XX.mlx
- Source data

$$U_{s_rated} = 75$$

$$n_{rated} = 600$$

$$f_{sw} = 1.21e + 03$$

$$R_{a} = 0.075$$

$$L_a = 5.54 \text{e} - 04$$

$$J_S = 0.238$$

$$I_{a \ rated} = 50$$

$$k_{i \ lim} = 1.8$$

- Rated source voltage, V;
- Rated rotating speed, rpm;
 - PWM frequency, Hz;
- Resistance of DC machine winding, Ω ;
 - Armature inductance, H;
 - Moment of inertia, $kg \cdot m^2$;
- Anchor rated current of DC machine, A;
- Maximum current limit, A.

Evaluations:

$$P = U_{s \ rated} \cdot I_{a \ rated} = 3750$$

$$I_{a_sc} = \frac{U_{s_rated}}{R_a} = 1000$$

$$W_{m_rated} = \frac{2 \cdot \pi \cdot n_{rated}}{60} = 62.8319$$

$$k_e = \frac{(U_{s_rated} - R_a \cdot I_{a_rated})}{w_{m_rated}} = 1.134$$

$$k_m = k_e$$

$$T_{e_rated} = k_m \cdot I_{a_rated} = 56.69$$

$$T_{e_max} = k_{lim} \cdot T_{e_rated} = 102.0581$$

$$T_{e_st} = k_m \cdot I_{a_sc} = 1.13e + 03$$

$$K_{eff_rated} = \frac{w_{m_rated} \cdot T_{e_rated}}{P} \cdot 100\% = 95$$
 - Rated efficiency, %;

$$\tau_e = \frac{L_a}{R_a} = 0.0074$$

$$w_0 = \frac{U_{s_rated}}{k_e} = 66.1388$$

$$\tau_m = \frac{J_s \cdot w_0}{T_{e,st}} = 0.0139$$

- Power, W:
- Short circuit current, A;
- Rated rotating speed, rad/s;
- EMF constant, V*s/rad;
- Electromechanical constant, N · m /A;
- Rated Torque of the DC machine, N·m;
 - Maximum torque, N · m;
 - Starting torque, N · m;
- - Electromagnetic time constant, s;
 - Idle speed, rad/s;
 - Electromechanical time constant, s

Part 2. Evaluate parameters of the system with PWM

Transistor switched on circuit parameters

$$V_{f_{vt}} = 0$$
 - IGBT Forward voltage V_f at current $I_a \approx 0$, [V] (For MOSFET may be considered equal to 0); - Forward voltage V_f at current $I_a = I_{lim} = I_{a_rated} \cdot k_{lim}$, [V]; $I_a = I_{lim} = I_{a_rated} \cdot k_{lim}$, [V]; - MOSFET / IGBT resistance $I_a = I_{lim} = I_{a_rated} \cdot I_{lim}$ - MOSFET / IGBT resistance $I_a = I_{lim} = I_{a_rated} \cdot I_{lim}$ - MOSFET / IGBT resistance $I_a = I_{lim} = I_{a_rated} \cdot I_{lim}$ - MOSFET / IGBT resistance $I_a = I_{lim} = I_{a_rated} \cdot I_{lim}$ - MOSFET / IGBT resistance $I_a = I_{lim} = I_{a_rated} \cdot I_{lim}$

Snubber circuit parameters

$$C_S = 330e-9$$
 - Snubber capacitance, [F];
 $R_S = 1e6$ - Snubber resistance, [Ω];

Reverse (antiparallel) diode parameters

$$V_{f_{rd}} = 0.85$$
 - Internal (antiparallel) diode forward voltage V_f at current $I_a \approx 0$, [V]; $V_{f_{rd_{Ia}}} = 0.95$ - Internal (antiparallel) diode forward voltage at current I_{lim} , [V]; $R_{on_{rd}} = \frac{(V_{f_{rd_{Ia}}} - V_{f_{rd}})}{I_{lim}} = 0.0011$ - Internal (antiparallel) diode resistance R_d , [Ω];

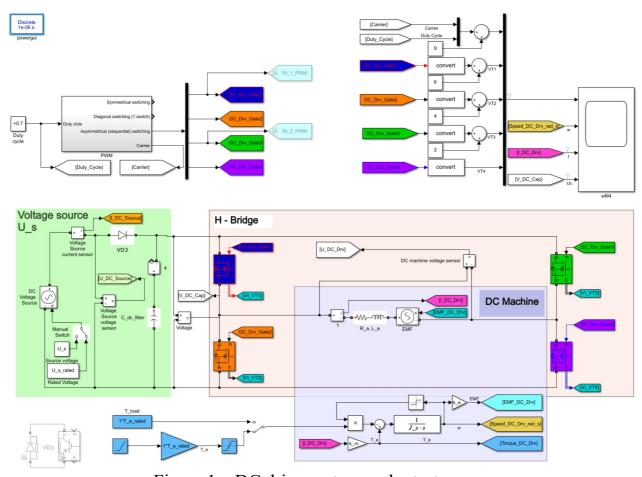


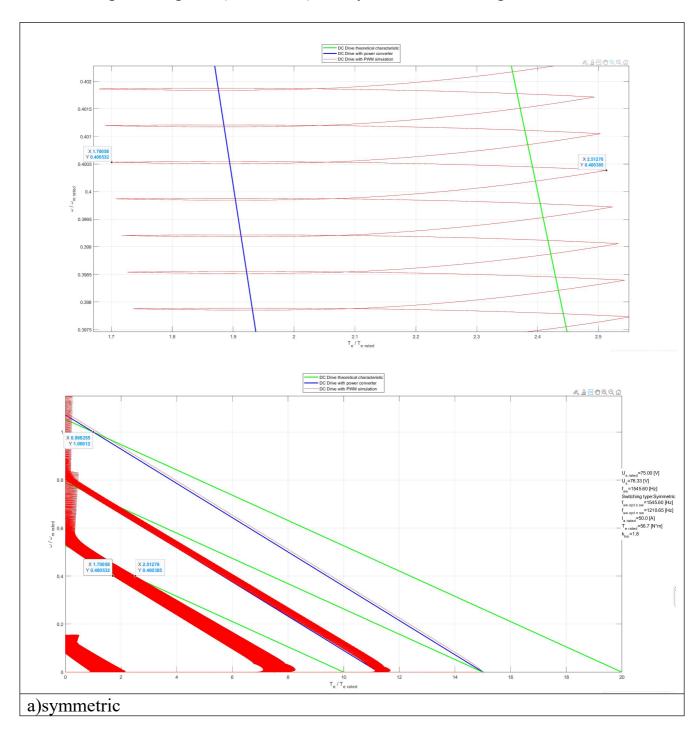
Figure 1 – DC drive system under test

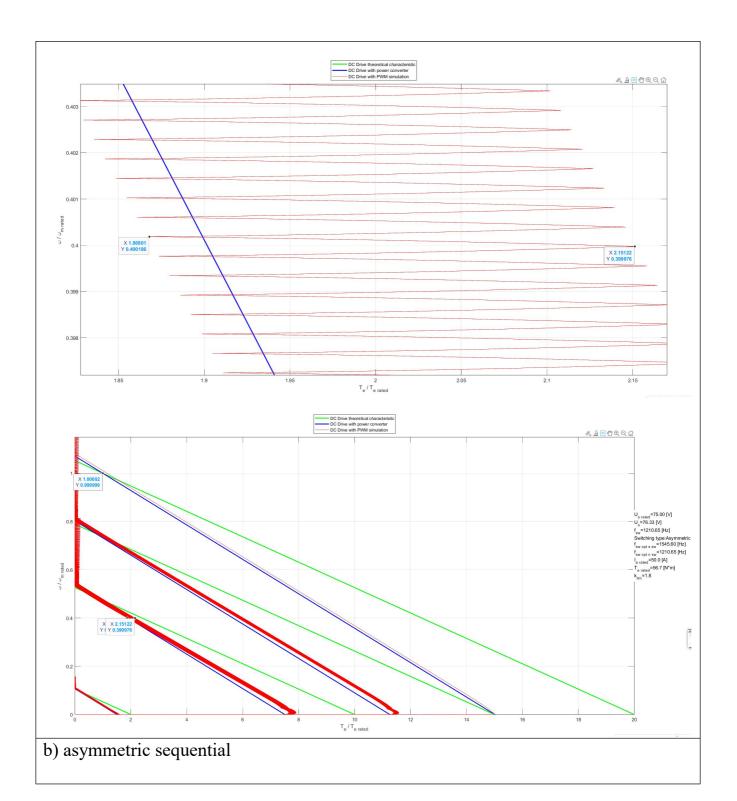
Part 3. Simulation results

NB! Duty cycles values are in your variant data: as $gamma_all$ values.

[1; 0.75; 0.5; 0.1]

• Compare diagonal (one switch) and symmetric switching





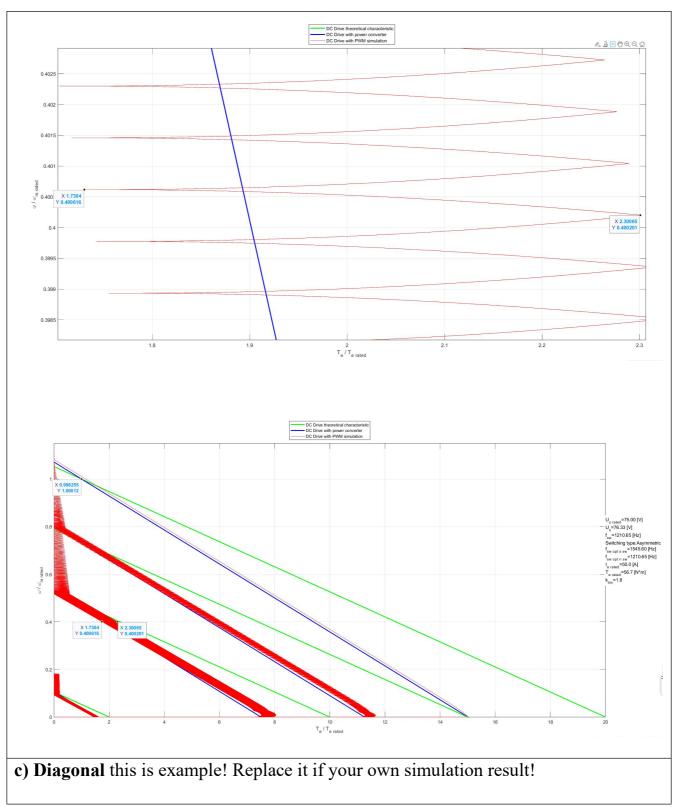
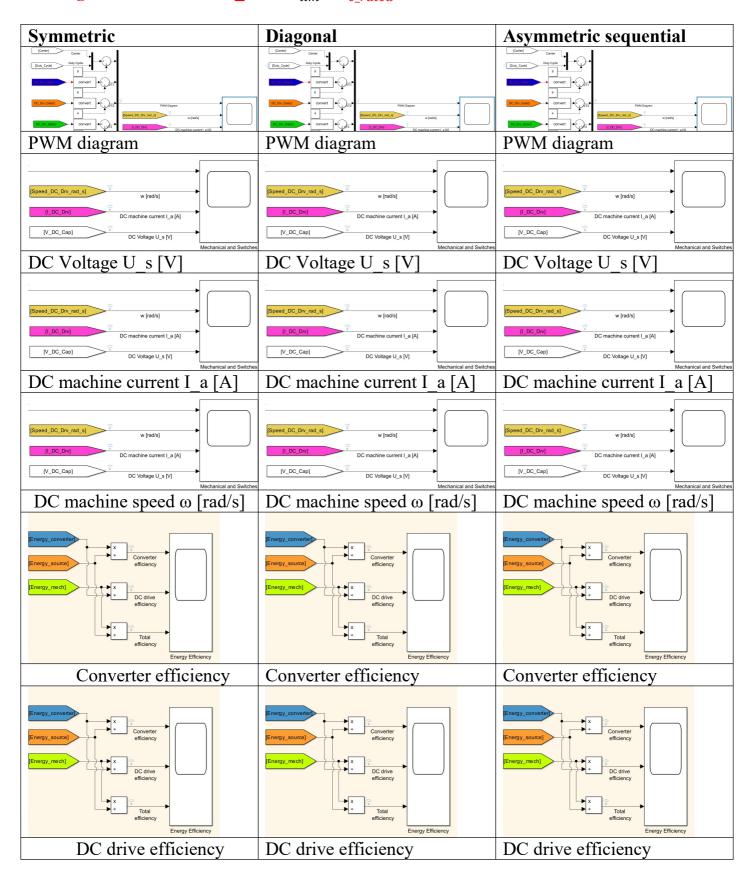


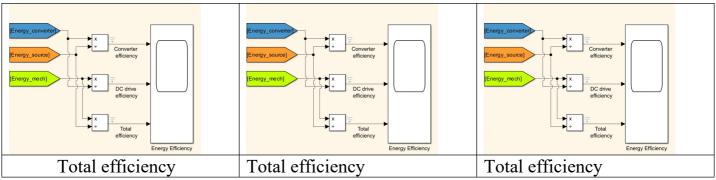
Figure 2 – DC drive mechanical characteristics

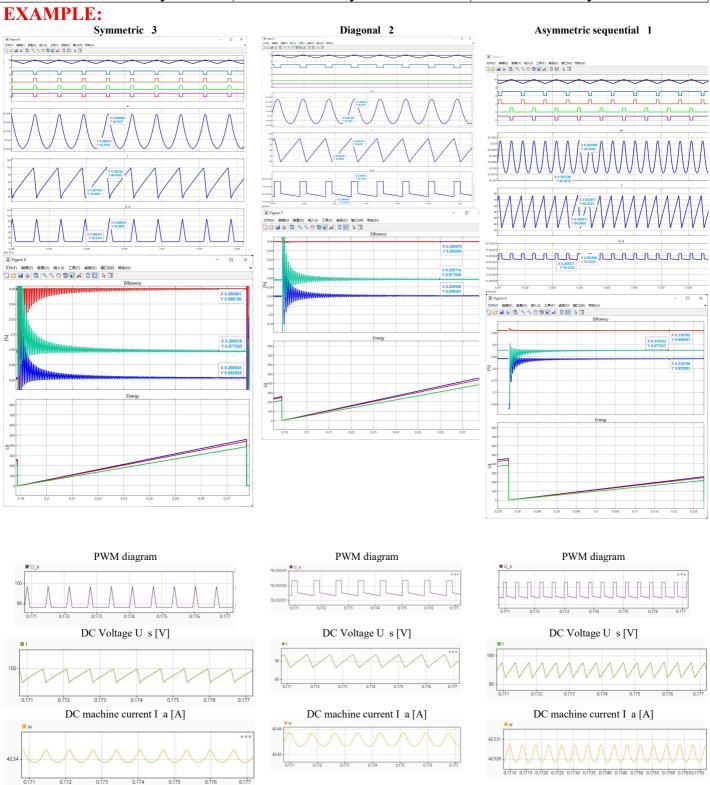
NB! with new parameters your result will be slightly different!

Part 4. Simulation results

• Analyze drive parameters with different pulse width with duty cycle gamma= 0.75 and T_load= $k_{lim}*T_{e_rated}$







DC machine speed ω [rad/s]

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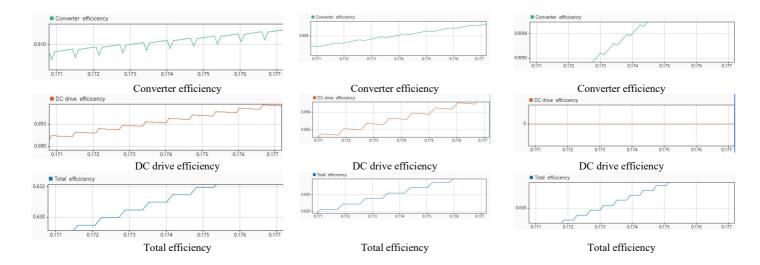


Figure 3 – DC Drive with PWM converter efficiency

Optimal switching frequency evaluation (symmetrical switching)

$$f_{sw_opt} = 0.332 \sqrt[3]{\frac{\alpha_K r_a^2}{L_a^2 (t_+ + t_-)}} = 1540$$
 Hz

Optimal switching frequency evaluation (non-symmetrical sequentional and diagonal switching)

$$f_{sw_opt} = 0.26 \sqrt[3]{\frac{\alpha_K r_a^2}{L_a^2(t_+ + t_-)}} = 1210$$
 Hz

- Analyze drive parameters with different pulse width with
- duty cycle (gamma)= 0.75 and T_load= $T_{e_max} = k_{lim} * T_{e_rated}$

Conclusions

Results of comparison efficiency, current and speed ripple in case of symmetrical, diagonal, and sequential switching.

Symmetric switching:

Achieved the highest overall efficiency, with the lowest ripple observed in both armature current (Ia) and rotational speed (ω).

Voltage remained stable with minimal fluctuation.

It offers smooth and precise motor control, making it the most stable method among the three.

Peak performance occurs at an optimal switching frequency of approximately 1540 Hz.

Diagonal switching:

Exhibited significant current ripple, caused by asymmetric current paths.

This also led to moderate ripple in speed, making motor response less stable.

Efficiency dropped by 5–8% compared to symmetric switching due to increased switching and conduction losses.

Suitable for cost-sensitive designs where control performance is not critical.

Asymmetric sequential switching:

Showed intermediate performance in terms of current and speed ripple—better than diagonal, but still less optimal than symmetric.

Efficiency was slightly higher than diagonal at low switching frequencies (~1210 Hz), making it a practical compromise for systems with varying load dynamics.